

SN5410, SN54LS10, SN54S10 SN7410, SN74LS10, SN74S10

Triple 3-Input Positive-Nand Gates

The SN5410, SN54LS10, and SN54S10 are characterized for operation over the full military temperature range of -55°C to +125°C. The SN7410, SN74LS10, and SN74S10 are characterized for operation from 0°C to +70°C. These devices contain three independent 3-input NAND gates.

Rochester Electronics Manufactured Components

Rochester branded components are manufactured using either die/wafers purchased from the original suppliers or Rochester wafers recreated from the original IP. All recreations are done with the approval of the OCM.

Parts are tested using original factory test programs or Rochester developed test solutions to guarantee product meets or exceeds the OCM data sheet.

Quality Overview

- ISO-9001
- AS9120 certification
- Qualified Manufacturers List (QML) MIL-PRF-35835
 - Class Q Military
 - Class V Space Level
- Qualified Suppliers List of Distributors (QSLD)
 - Rochester is a critical supplier to DLA and meets all industry and DLA standards.

Rochester Electronics, LLC is committed to supplying products that satisfy customer expectations for quality and are equal to those originally supplied by industry manufacturers.

The original manufacturer's datasheet accompanying this document reflects the performance and specifications of the Rochester manufactured version of this device. Rochester Electronics guarantees the performance of its semiconductor products to the original OEM specifications. 'Typical' values are for reference purposes only. Certain minimum or maximum ratings may be based on product characterization, design, simulation, or sample testing.

SN5410, SN54LS10, SN54S10, SN7410, SN74LS10, SN74S10 TRIPLE 3-INPUT POSITIVE-NAND GATES

DECEMBER 1983—REVISED MARCH 1988

- Package Options Include Plastic "Small Outline" Packages, Ceramic Chip Carriers and Flat Packages, and Plastic and Ceramic DIPs
- Dependable Texas Instruments Quality and Reliability

description

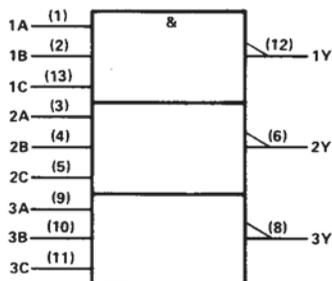
These devices contain three independent 3-input NAND gates.

The SN5410, SN54LS10, and SN54S10 are characterized for operation over the full military temperature range of -55°C to 125°C . The SN7410, SN74LS10, and SN74S10 are characterized for operation from 0°C to 70°C .

FUNCTION TABLE (each gate)

INPUTS			OUTPUT
A	B	C	Y
H	H	H	L
L	X	X	H
X	L	X	H
X	X	L	H

logic symbol†



† This symbol is in accordance with ANSI/IEEE Std. 91-1984 and IEC Publication 617-12.

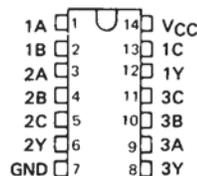
Pin numbers shown are for D, J, and N packages.

positive logic

$$Y = \overline{A \cdot B \cdot C} \text{ or } Y = \overline{A} + \overline{B} + \overline{C}$$

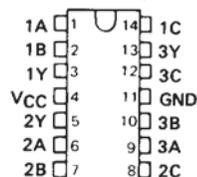
SN5410 . . . J PACKAGE
SN54LS10, SN54S10 . . . J OR W PACKAGE
SN7410 . . . N PACKAGE
SN74LS10, SN74S10 . . . D OR N PACKAGE

(TOP VIEW)



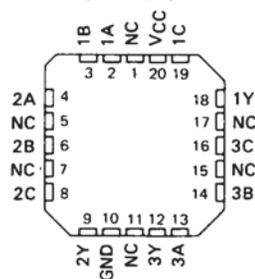
SN5410 . . . W PACKAGE

(TOP VIEW)



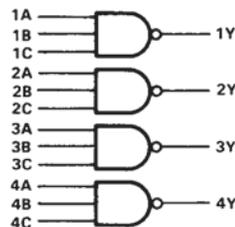
SN54LS10, SN54S10 . . . FK PACKAGE

(TOP VIEW)



NC - No internal connection

logic diagram (positive logic)



PRODUCTION DATA documents contain information current as of publication date. Products conform to specifications per the terms of Texas Instruments standard warranty. Production processing does not necessarily include testing of all parameters.

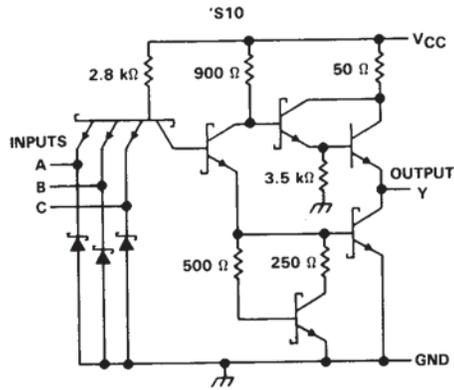
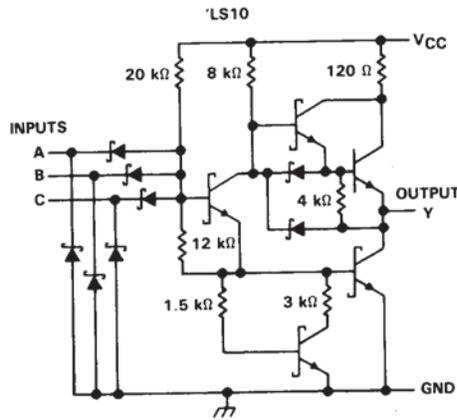
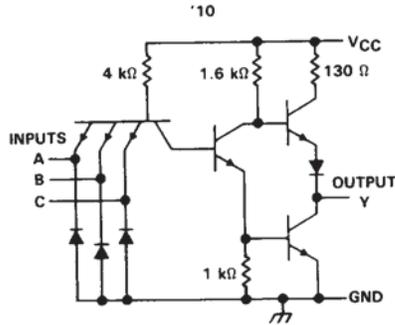
TEXAS
INSTRUMENTS

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**SN5410, SN54LS10, SN54S10,
SN7410, SN74LS10, SN74S10
TRIPLE 3-INPUT POSITIVE-NAND GATES**

schematics (each gate)

2
TTL Devices



Resistor values shown are nominal.

absolute maximum ratings over operating free-air temperature range (unless otherwise noted)

Supply voltage, VCC (see Note 1)	7 V
Input voltage: '10, 'S10	5.5 V
'LS10	7 V
Operating free-air temperature range: SN54'	-55°C to 125°C
SN74'	0°C to 70°C
Storage temperature range	-65°C to 150°C

NOTE 1: Voltage values are with respect to network ground terminal.

SN5410, SN7410
TRIPLE 3-INPUT POSITIVE-NAND GATES

recommended operating conditions

	SN5410			SN7410			UNIT
	MIN	NOM	MAX	MIN	NOM	MAX	
V _{CC} Supply voltage	4.5	5	5.5	4.75	5	5.25	V
V _{IH} High-level input voltage	2			2			V
V _{IL} Low-level input voltage			0.8			0.8	V
I _{OH} High-level output current			-0.4			-0.4	mA
I _{OL} Low-level output current			16			16	mA
T _A Operating free-air temperature	-55		125	0		70	°C

electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER	TEST CONDITIONS †	SN5410			SN7410			UNIT
		MIN	TYP‡	MAX	MIN	TYP‡	MAX	
V _{IK}	V _{CC} = MIN, I _I = -12 mA		-1.5			-1.5	V	
V _{OH}	V _{CC} = MIN, V _{IL} = 0.8 V, I _{OH} = -0.4 mA	2.4	3.4		2.4	3.4	V	
V _{OL}	V _{CC} = MIN, V _{IH} = 2 V, I _{OL} = 16 mA		0.2	0.4		0.2	0.4	V
I _I	V _{CC} = MAX, V _I = 5.5 V		1			1	mA	
I _{IH}	V _{CC} = MAX, V _I = 2.4 V		40			40	µA	
I _{IL}	V _{CC} = MAX, V _I = 0.4 V		-1.6			-1.6	mA	
I _{OS} §	V _{CC} = MAX	-20		-55	-18		-55	mA
I _{CCH}	V _{CC} = MAX, V _I = 0 V		3	6		3	6	mA
I _{CCL}	V _{CC} = MAX, V _I = 4.5 V		9	16.5		9	16.5	mA

† For conditions shown as MIN or MAX, use the appropriate value specified under recommended operating conditions.

‡ All typical values are at V_{CC} = 5 V, T_A = 25°C.

§ Not more than one output should be shorted at a time.

switching characteristics, V_{CC} = 5 V, T_A = 25°C (see note 2)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	TEST CONDITIONS	MIN	TYP	MAX	UNIT
t _{PLH}	A, B or C	Y	R _L = 400 Ω, C _L = 15 pF		11	22	ns
t _{PHL}					7	15	ns

NOTE 2: Load circuits and voltage waveforms are shown in Section 1.

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TTL Devices

SN54LS10, SN74LS10
TRIPLE 3-INPUT POSITIVE-NAND GATES

recommended operating conditions

	SN54LS10			SN74LS10			UNIT
	MIN	NOM	MAX	MIN	NOM	MAX	
V _{CC} Supply voltage	4.5	5	5.5	4.75	5	5.25	V
V _{IH} High-level input voltage	2			2			V
V _{IL} Low-level input voltage	0.7			0.8			V
I _{OH} High-level output current	-0.4			-0.4			mA
I _{OL} Low-level output current	4			8			mA
T _A Operating free-air temperature	-55 125			0 70			°C

electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER	TEST CONDITIONS †	SN54LS10			SN74LS10			UNIT
		MIN	TYP‡	MAX	MIN	TYP‡	MAX	
V _{IK}	V _{CC} = MIN, I _I = -18 mA	-1.5			-1.5			V
V _{OH}	V _{CC} = MIN, V _{IL} = MAX, I _{OH} = -0.4 mA	2.5	3.4		2.7	3.4		V
V _{OL}	V _{CC} = MIN, V _{IH} = 2 V, I _{OL} = 4 mA	0.25 0.4			0.4			V
	V _{CC} = MIN, V _{IH} = 2 V, I _{OL} = 8 mA				0.25 0.5			
I _I	V _{CC} = MAX, V _I = 7 V	0.1			0.1			mA
I _{IH}	V _{CC} = MAX, V _I = 2.7 V	20			20			µA
I _{IL}	V _{CC} = MAX, V _I = 0.4 V	-0.4			-0.4			mA
I _{OS} §	V _{CC} = MAX	-20		-100	-20		-100	mA
I _{CCH}	V _{CC} = MAX, V _I = 0 V	0.6 1.2			0.6 1.2			mA
I _{CCL}	V _{CC} = MAX, V _I = 4.5 V	1.8 3.3			1.8 3.3			mA

† For conditions shown as MIN or MAX, use the appropriate value specified under recommended operating conditions.

‡ All typical values are at V_{CC} = 5 V, T_A = 25°C.

§ Not more than one output should be shorted at a time, and the duration of the short-circuit should not exceed one second.

switching characteristics, V_{CC} = 5 V, T_A = 25°C (see note 2)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	TEST CONDITIONS	MIN	TYP	MAX	UNIT
t _{PLH}	A, B or C	Y	R _L = 2 kΩ, C _L = 15 pF	9		15	ns
t _{PHL}				10		15	ns

NOTE 2: Load circuits and voltage waveforms are shown in Section 1.

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TTL Devices

SN54S10, SN74S10
TRIPLE 3-INPUT POSITIVE-NAND GATES

recommended operating conditions

	SN54S10			SN74S10			UNIT
	MIN	NOM	MAX	MIN	NOM	MAX	
V _{CC} Supply voltage	4.5	5	5.5	4.75	5	5.25	V
V _{IH} High-level input voltage	2			2			V
V _{IL} Low-level input voltage	0.8			0.8			V
I _{OH} High-level output current	-1			-1			mA
I _{OL} Low-level output current	20			20			mA
T _A Operating free-air temperature	-55	125		0	70		°C

electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER	TEST CONDITIONS †	SN54S10			SN74S10			UNIT
		MIN	TYP‡	MAX	MIN	TYP‡	MAX	
V _{IK}	V _{CC} = MIN, I _I = -18 mA			-1.2			-1.2	V
V _{OH}	V _{CC} = MIN, V _{IL} = 0.8 V, I _{OH} = -1 mA	2.5	3.4		2.7	3.4		V
V _{OL}	V _{CC} = MIN, V _{IH} = 2 V, I _{OL} = 20 mA			0.5			0.5	V
I _I	V _{CC} = MAX, V _I = 5.5 V			1			1	mA
I _{IH}	V _{CC} = MAX, V _I = 2.7 V			50			50	µA
I _{IL}	V _{CC} = MAX, V _I = 0.5 V			-2			-2	mA
I _{OS} §	V _{CC} = MAX	-40		-100	-40		-100	mA
I _{CCH}	V _{CC} = MAX, V _I = 0 V		7.5	12		7.5	12	mA
I _{CCL}	V _{CC} = MAX, V _I = 4.5 V		15	27		15	27	mA

† For conditions shown as MIN or MAX, use the appropriate value specified under recommended operating conditions.

‡ All typical values are at V_{CC} = 5 V, T_A = 25°C.

§ Not more than one output should be shorted at a time, and the duration of the short-circuit should not exceed one second.

switching characteristics, V_{CC} = 5 V, T_A = 25°C (see note 2)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	TEST CONDITIONS	MIN	TYP	MAX	UNIT
t _{PLH}	A, B or C	Y	R _L = 280 Ω, C _L = 15 pF		3	4.5	ns
t _{PHL}					3	5	ns
t _{PLH}			R _L = 280 Ω, C _L = 50 pF		4.5		ns
t _{PHL}					5		ns

NOTE 2: Load circuits and voltage waveforms are shown in Section 1.

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TTL Devices